From Growth Surface to Device Interface: Preserving Metallic Fe under Monolayer Hexagonal Boron Nitride

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Supporting Information

ABSTRACT: We investigate the interfacial chemistry between Fe catalyst foils and monolayer hexagonal boron nitride (h-BN) following chemical vapor deposition and during subsequent atmospheric exposure, using scanning electron microscopy, X-ray photoemission spectroscopy, and scanning photoelectron microscopy. We show that regions of the Fe surface covered by h-BN remain in a metallic state during exposure to moist air for ~40 h at room temperature. This protection is attributed to the strong interfacial interaction between h-BN and Fe, which prevents the rapid intercalation of oxidizing species. Local Fe oxidation is observed on bare Fe regions and close to defects in the h-BN film (e.g., domain boundaries, wrinkles, and edges), which over the longer-term provide pathways for slow bulk oxidation of Fe. We further confirm that the interface between h-BN and metallic Fe can be recovered by vacuum annealing at ~600 °C, although this is accompanied by the creation of defects within the h-BN film. We discuss the importance of these findings in the context of integrated manufacturing and transfer-free device integration of h-BN, particularly for technologically important applications where h-BN has potential as a tunnel barrier such as magnetic tunnel junctions.

KEYWORDS: hexagonal boron nitride (h-BN), iron (Fe), interfacial chemistry, X-ray photoelectron spectroscopy (XPS), chemical vapor deposition (CVD)

INTRODUCTION

Hexagonal boron nitride (h-BN), the isostructural and electrically insulating counterpart to graphene, is technologically promising not only as a support for high-mobility graphene and other two-dimensional (2D) materials but also, given its low permeability to gases and thermochemical stability,2–4 as an ultimately thin barrier layer for integrated electronics, photonics, and spintronics.5–8 A critical requirement for numerous emerging device concepts is that, as well as the h-BN layers being of high crystalline quality, their interface to other materials must be clean and well-controlled. Although significant progress has been made in 2D material crystal growth,7,9 particularly regarding scalable synthesis of h-BN films by chemical vapor deposition (CVD),10–14 clean interfacing and scalable device integration remain major challenges. The latter typically involves transfer of the atomically thin h-BN layers away from the CVD growth substrate; hence, the choice of CVD catalyst/substrate and the related interfacial chemistry must be optimized toward ease of release of the h-BN.15 Nevertheless, the potential for structural damage and contamination during transfer remains,16 and avoiding this step offers a cleaner and simpler process flow that is more amenable to integrated manufacturing.

Transfer-free h-BN integration requires direct, conformal h-BN deposition onto a device-relevant substrate. This has been demonstrated for instance for vertical magnetic tunnel junctions (MTJs), where the bottom ferromagnetic device layer acts as a catalytic growth substrate for h-BN CVD.6 Although previous literature focused mainly on the quality of as-grown h-BN, crucial for this approach is also that the device substrate is not negatively affected by the CVD process and that the resulting interface remains stable during further processing. The latter links to the question of how effectively 2D materials can protect different substrates. For graphene, this has been investigated in detail and shown to relate to the strength of interaction between graphene and the substrate.17 Strongly interacting transition metals, such as Ni and Fe, with a significant degree of hybridization between the graphene π

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states and the d band states of the metal\textsuperscript{18–20} prevent the rapid intercalation of oxidizing species at the graphene–metal interface and thus suppress oxidation and protect the metal surface. This protection can preserve clean, metallic interfaces, which is a crucial requirement for effective spin injectors, and the importance of this has been demonstrated for graphene-based MTJs.\textsuperscript{21–23} Recent literature highlights that h-BN as a tunnel barrier may outperform widely used oxide barriers\textsuperscript{6,25} and when paired with a metallic ferromagnet can allow effective spin-filtering.\textsuperscript{6,26–29} A tunnel magnetoresistance of up to 6% has already been demonstrated for a MTJ based on a single h-BN layer grown directly on the Fe electrode.\textsuperscript{6} Although high-quality h-BN CVD on Fe has been reported and it has been shown how boride and nitride formation in the Fe bulk can be avoided,\textsuperscript{10,11} the nature and stability of as-grown h-BN/Fe interfaces, which are of utmost importance to device integration, have not been studied in detail.

Here, we use scanning electron microscopy (SEM), X-ray photoemission spectroscopy (XPS), and scanning photoelectron microscopy (SPEM) to systematically study the interfacial chemistry between Fe and h-BN after CVD and during subsequent atmospheric exposure. This model system has been chosen based on its particular relevance to MTJ device applications. Our SPEM data reveals that the Fe under h-BN is protected from oxidation under ambient conditions for several days. The single-layer h-BN provides a low-permeability barrier that restricts the access of oxidizing species to the metal surface, and the strong interaction between h-BN and Fe prevents the rapid intercalation of oxidizing species at the h-BN/Fe interface. However, Fe does not form a passivating oxide when exposed to moist air; therefore, during continuing exposure, the slow oxidation of the metal can proceed through the oxide layers formed in the vicinity of h-BN edges and defects. We further demonstrate that a h-BN/metallic-Fe interface can be recovered by vacuum annealing of a sample exposed to air for 7 days, with the reduction of Fe confirmed by XPS. We find that the general rationale for effective passivation by h-BN is consistent with a model developed for graphene\textsuperscript{17} and discuss the importance of our findings in the context of transfer-free h-BN device integration and MTJ applications where the protection demonstrated ensures a window for device processing in air and other oxidizing environments.

**RESULTS**

We investigate the time-dependent oxidation behavior of polycrystalline Fe foils (100 \(\mu\)m thick) that have single-layer h-BN grown directly on their surface by CVD and are subsequently exposed to atmospheric air at room temperature. All growths are performed in a customized CVD reactor (base pressure 10\textsuperscript{-6} mbar) with the Fe foils preannealed in NH\textsubscript{3} (4 mbar) at \(\sim\)900 °C to B\textsubscript{3}N\textsubscript{3}H\textsubscript{6} exposure at the same temperature. The preannealing enriches the Fe bulk with N, promoting the exclusive growth of single-layer h-BN on the catalyst surface and avoiding any Fe-boride formation.\textsuperscript{11}

**Figure 1** compares SEM images of discontinuous domains (a–c) and complete films (d–f) of single-layer h-BN on the Fe catalyst that have been exposed to air for different times following growth. The dark triangles in Figure 1a correspond to single-layer h-BN after 30 min of air exposure. After 1 day, thin bright veins can be observed crossing the domains (Figure 1b). We have previously shown by dark field transmission electron microscopy that the individual, triangular h-BN islands are single crystals;\textsuperscript{11} therefore, the bright veins are expected to relate to wrinkling of h-BN caused by the thermal expansion mismatch with the underlying Fe rather than to domain boundaries in h-BN.\textsuperscript{30} After 7 days in air, the brighter regions are found to have grown at the expense of the darker regions within the domains. The inset shows a high-magnification image of a small isolated h-BN domain, which reveals a band of brighter contrast around the perimeter, indicating that the contrast change proceeds inward from the edges.

**Figure 1g** shows the morphology of a complete single-layer h-BN film (i.e., without bare Fe regions) after 30 min, 1 day, and 7 days of air exposure. The SEM contrast is again seen to evolve over time, from dark to bright. Following 30 min of air exposure, the h-BN/Fe interface is uniform and dark within each Fe grain. We note that the relatively minor grain-to-grain contrast variations of the Fe catalyst are related to the electron channeling contrast routinely observed for polycrystalline metal surfaces and do not reflect a variation in the thickness of h-BN.\textsuperscript{31} After 1 day, we again observe bright lines spreading across the surface, and after 7 days, the bright regions surround the few dark areas remaining. **Figure S1** shows in more detail a representative area of the h-BN film after 1 day in air, where a network of brighter channels is apparent, from which the change in secondary electron contrast proceeds. Given the contrast between the middle of the domains (black, region 1), domain edges (light gray, region 2), and the uncovered Fe catalyst (dark gray, region 3). (h) False color SEM image showing the detail of bow-tie-shaped h-BN domains after 1 day of air exposure and (i) corresponding schematic indicating that the change of contrast initiates at the domain edges and domain boundaries (dotted line) and proceeds inward. h-BN\textsubscript{BAC} and h-BN\textsubscript{BNC} indicate h-BN covering metallic and oxidized Fe regions, respectively.

**Figure 1.** (a–c) h-BN domains on the Fe substrate after 30 min, 1 day, and 7 days of air exposure, respectively. (d–f) h-BN film on the Fe substrate after 30 min, 1 day, and 7 days of air exposure, respectively. h-BN was grown at \(\sim\)900 °C, by B\textsubscript{3}N\textsubscript{3}H\textsubscript{6} (6 \(\times\) 10\textsuperscript{-4} mbar) exposure for 45 s (domains) or 12 min (films). (g) Detail of merging h-BN domains (left, right, and top) after 7 days of air exposure, illustrating a contrast difference between the middle of the domains (black, region 1), domain edges (light gray, region 2), and the uncovered Fe catalyst (dark gray, region 3). (h) False color SEM image showing the detail of bow-tie-shaped h-BN domains after 1 day of air exposure and (i) corresponding schematic indicating that the change of contrast initiates at the domain edges and domain boundaries (dotted line) and proceeds inward. h-BN\textsubscript{BAC} and h-BN\textsubscript{BNC} indicate h-BN covering metallic and oxidized Fe regions, respectively.
interesting to note that the brightest regions (region 2, shaded red), although having lost their initial dark contrast (i.e., region 1), still bear the shape of the sharp h-BN domain edges, which can be distinguished from the areas of bare Fe (region 3).

Figure 1h shows a false-colored SEM image of a “bow tie” h-BN domain structure, where two triangular domains have partially coalesced, creating a domain boundary at the merging front. The domain edges and the domain-boundary region display a different contrast, suggesting that the contrast changes proceed inward from locations at which the atmosphere can more easily access the Fe foil, such as through edges and the defects present at boundaries (Figure 1i).31,32

We confirm that the change in SEM contrast is not indicative of a loss of h-BN material by transferring fresh h-BN domains (30 min air exposure) and aged domains (7 day air exposure) onto SiO2(300 nm)/Si wafers. The optical images in Figure 2a,b demonstrate that the triangular shapes and sizes of the h-BN domains are preserved and are very similar to those of the domains grown on the catalyst (Figure 1a). The corresponding Raman spectra (Figure 2c) show very similar signatures for both samples, confirming that h-BN is present on both and retains similar structural quality insofar as Raman spectroscopy is sensitive to this. Additionally, the XP B 1s and N 1s core-level spectra for a nontransferred sample (i.e., h-BN/Fe) exposed to air for ∼40 h (Figure S2) exhibit a dominant B/N peak pair at 190.2/397.8 eV, which can be attributed to high-quality monolayer h-BN.11 This combined with the absence of any peak at ∼193 eV in the B 1s core level, the typical position of boron oxide species,33 indicates that the intrinsic chemical structure of h-BN is not significantly altered by atmospheric air exposure.

Further evidence that h-BN is stable in air at room temperature over time is obtained without a transfer step, by vacuum annealing [∼600 °C for 1 h (<10−5 mbar)] of a sample after 7 days of air exposure, as illustrated in Figure 3a−f. The behavior observed is schematically summarized in (a)−(c), with the corresponding SEM images shown in (d)−(f). At the onset of air exposure, the h-BN domains on the metal surface show relatively homogeneous dark contrast (Figure 3a,d). With continued air exposure, this contrast is gradually lost (Figure 3b,e). On vacuum annealing at ∼600 °C, the domains recover dark contrast similar to that observed for the fresh h-BN samples immediately after CVD (Figure 3c,f), further demonstrating that despite the changes in contrast h-BN remains intact. In situ XPS measurements of similar samples during vacuum annealing at ∼600 °C show no emergence of a boron oxide-related peak at ∼193 eV nor any detectable oxygen species in the O 1s region, confirming the effective reduction of Fe without oxidation of h-BN (see Figure S3). However, XPS measurements after a further air exposure reveal some oxidation of the h-BN films, as manifested by the appearance of a boron oxide peak at ∼193 eV. This therefore indicates that the
annealing process has led to some degradation of h-BN, with defects formed, which are then oxidized on air exposure.

Figure 4a,b shows XP spectra of the Fe 2p1/2 core level for a complete h-BN film and discontinuous domains, respectively as a function of air exposure time. After 1 day in air, the spectrum for the complete film displays a dominant metallic peak at 706.7 eV (FeM) and negligible oxide-related components, indicating that the Fe is well reduced. After 7 days, Fe is still mainly in the reduced state; however, a small peak at the oxide position emerges above the noise level, at ~711 eV (FeOX), which is indicative of slight oxidation. This behavior is in strong contrast to that of bare Fe, where significant oxidation of the surface is observed following air exposures of just 1 h but is in excellent agreement with our previous studies on air-exposed graphene-coated Fe substrates, where gradual oxidation of the metal is observed. For discontinuous h-BN domains (Figure 4b), the spectral components related to both metallic and oxidized Fe are observed following 1 day of air exposure. The metallic peak dominates over the oxide-related peak, indicating that Fe remains predominantly reduced, consistent with the fact that only the exposed Fe regions oxidize, whereas the h-BN-covered regions remain reduced. However, after 7 days, the extent of Fe oxidation is significantly increased, as revealed by the greater intensity of the oxide components relative to the metal peak.

Figure 5a shows a SPEM map of h-BN domains grown on Fe foil (same growth conditions as in Figure 1a) acquired for the B 1s core-level energy, following exposure to atmospheric air for ~40 h at room temperature. The schematic in the inset indicates that the light gray triangles correspond to h-BN domains and the surrounding dark areas correspond to the bare Fe surface, as subsequently confirmed by the maps in Figure 5c,d. XP spectra of the Fe 2p1/2 core level were acquired on the bare Fe (region A) and on a h-BN domain (region B), as shown in Figure 5b. The change in spectral components present in these two regions indicates a distinct difference in the oxidation state of Fe between the h-BN-covered regions and bare Fe.

The peaks from region A are attributable to the Fe oxide/oxyhydroxide species (FeOX)34 whereas the peaks from region B correspond to metallic Fe (FeM). Figure 5c–e shows the elemental maps of the edge and tips of several h-BN domains and the neighboring bare Fe surface using the B 1s and N 1s maps, the right-hand side of the image appears brighter, indicating a higher signal originating from this area, which confirms h-BN coverage of this region. We note that a Fe grain boundary can be seen crossing slightly diagonally from the top to the bottom of Figure 5c,d across several h-BN domains, which is apparent due to topographic changes in the XP signal. Figure 5e, which depicts a map of the ratio between the metal and oxide components of the Fe 2p1/2 core level, is a background-corrected chemical map (see Methods) where the intensity changes generated by the topography of the sample are intrinsically removed, thus revealing only chemical data. The brightest contrast, that is the predominantly metallic Fe, corresponds to the h-BN-covered region on the right-hand side, confirming that oxidation protection arises from the h-BN coverage. The fact that the contrast level is also maintained across the Fe grain boundary indicates that the extent of protection afforded by the h-BN layer is maintained in spite of the topography of the underlying substrate. Where h-BN is absent on the left-hand side of Figure 1e, the signal is less bright, confirming that the uncovered Fe is predominantly oxidized. The B 1s and N 1s chemical maps with the topographic component removed are shown in Figure S4.

DISCUSSION

The changes in SEM contrast observed in Figure 1 may at first sight appear to correspond to degradation of h-BN in air; however, our XPS and SPEM data confirm that they instead relate to the gradual oxidation of the Fe substrate beneath h-BN. Similar contrast changes are observed for graphene on weakly interacting metals due to the intercalation of oxidizing species, which alter the charge-transfer doping from the underlying substrate and thus the work function of the graphene, without otherwise significantly disturbing its band structure.32,35 In the case of h-BN on Fe, intercalation is suppressed due to the strong interaction between h-BN and the substrate, but as our XPS measurements here show, oxidation can still proceed through the Fe bulk. The changes in SEM contrast observed for h-BN-covered regions are therefore attributable to the different secondary electron yields of oxidized and metallic Fe, as well as possible variations in the work function associated with changes in hybridization between h-BN and the substrate (i.e., alteration of the h-BN band structure36–38) as the substrate oxidizes. The changes in the...
SEM contrast from dark to light with continuing air exposure are thus indicative of oxidation of the underlying metal. We can therefore assign the different contrast levels in Figure 1g to h-BN-covered metallic Fe (h-BN/FeM) in region 1, h-BN-covered oxidized Fe (h-BN/FeOX) in region 2, and bare Fe in region 3. The contrast changes apparent in Figure 1 thus correspond to Fe oxidation proceeding via domain edges, domain-boundary defects, and wrinkles of the h-BN layer, which serve as pathways for oxidizing species to reach the Fe surface during atmospheric air exposure. Given the detrimental effect of wrinkles on the passivation behavior of 2D films, we envisage that future work could be aimed at minimizing wrinkle formation during CVD growth by, for instance, varying the thickness of the catalyst, as has been reported for graphene CVD.39

The XPS spectra shown in Figure 4, acquired using a X-ray spot size of ∼150 μm, further confirm that oxidation proceeds through these pathways. In the case of the continuous h-BN film, the region probed is fully covered with h-BN and Figure 4a clearly confirms that Fe is protected from any substantial oxidation over the course of 1 day and that even after 7 days of air exposure the level of oxidation remains relatively low. For the discontinuous domains, the level of oxidation after 1 day is significantly increased, showing that the degree of protection depends on the extent of h-BN coverage. Furthermore, the increase in oxidation after 7 days is much more pronounced than for the continuous h-BN film, indicating that the increased prevalence of “open edges” allows oxidation to proceed more readily. However, as the XPS spot includes both covered and uncovered regions, we note that Figure 4b does not necessarily imply that the discontinuous h-BN domains do not locally protect Fe. This point is clarified by Figure 5 where spatially resolved XP spectra of the Fe 2p3/2 core level reveal that in the short term (∼40 h) significant oxidation (FeOX) is observed only in the regions of the surface that are not covered by h-BN, with the h-BN-covered regions remaining reduced (FeM).

The observed oxidation behavior can be understood in the context of the model recently introduced by Weatherup et al.17 to explain the behavior of different graphene/metal couples as a function of their interfacial interaction strength and the nature of the oxide formed by the substrate. Here, we extend this model to h-BN on Fe, as summarized in Figure 3, highlighting its general applicability to other 2D materials. During initial exposure to atmospheric air at room temperature, h-BN grown on Fe provides a low-permeability barrier that restricts the access of oxidizing species to the underlying metal. Furthermore, the strong interaction between h-BN and Fe prevents intercalation of oxidizing species at the h-BN–metal interface. Rapid oxidation thus occurs only at uncovered regions or close to intrinsic defects in the h-BN film (e.g., vacancies, grain boundaries) that provide pathways for oxidizing species to reach the substrate (shaded red, Figure 3a), whereas the areas with pristine h-BN coverage remain reduced (FeM). As discussed further below, Fe does not form a passivating oxide when exposed to moist air.49 Therefore, during continuing exposure (days), oxidation can proceed through the oxide layers formed in the vicinity of h-BN edges and defects (expanding FeOX region underneath the strongly coupled h-BN in Figure 3b), with Fe eventually becoming oxidized throughout. This process can be subsequently reversed by vacuum annealing, which leads to reduction of the Fe layer (Figure 3c). Our results herein for h-BN and previous work on graphene emphatically emphasize the importance of the interfacial interaction strength in effectively a 2D material protects...
a substrate. Therefore, we expect the development of methods to engineer this interfacial interaction strength, through techniques such as alloying or interfacial intercalation, to be a promising avenue for protecting material surfaces while retaining their functional (e.g., catalytic,\textsuperscript{41,42} plasmonic,\textsuperscript{43} and spin-filtering\textsuperscript{21–23}) properties.

In this work, we employ polycrystalline Fe foils comprising multiple crystal orientations and note that the h-BN domains readily grow across Fe grain boundaries. Furthermore, Fe can undergo a range of phase transformations and reactions with boron and nitrogen during the CVD process including upon cooling.\textsuperscript{41} The nature of the edge bonding and any epitaxial relationship will therefore vary across different Fe grains, within h-BN domains, and at different stages of the growth process, precluding here a simple explanation of the local oxidation behavior based on the interlayer distance, epitaxial relationship, or edge bonding state. The formation of wrinkles in the h-BN layer, which provide pathways between h-BN and Fe for more rapid surface oxidation, is also likely to be impacted by the complex phase behavior that the Fe surfaces undergo. Interestingly, we note that the general oxidation behavior of regions away from wrinkles appears similar across multiple h-BN domains on several samples. This indicates that the first-order picture of the oxidation behavior we develop, based on a strong Fe and h-BN hybridization preventing rapid intercalation of oxidizing species, is relevant across such complex polycrystalline surfaces.

Previous XPS studies on the behavior of polycrystalline Fe surfaces exposed to either oxygen or water vapor have elucidated the various stages of the oxidation mechanisms.\textsuperscript{44,45} In both cases, current interpretation suggests that a thin surface oxide initially forms by a place-exchange mechanism and then growth of the oxide proceeds by electric-field-driven diffusion of ions through vacancies, interstitial sites, and grain boundaries. As the oxide thickness increases, the electric field strength reduces, limiting the oxide thickness to several nanometers. A slower rate of oxide thickening is observed for \( \text{H}_2\text{O} \) compared to that for \( \text{O}_2 \), which is attributable to the presence of hydrogen, which restricts ion diffusion and occupies surface sites that would otherwise be available for further \( \text{H}_2\text{O} \) adsorption.\textsuperscript{45} When bare Fe is instead exposed to moist air containing both \( \text{O}_2 \) and \( \text{H}_2\text{O} \), a hydrated oxide forms as a loose deposit that provides very limited protection against further oxidation.\textsuperscript{40} Therefore, whereas a h-BN overlayer prevents oxidation of the Fe surface beneath for several days by acting as an impermeable barrier, Fe does not form an effective passivating oxide that can “plug” regions near h-BN defects and therefore oxidation proceeds through the Fe bulk over the longer term.

In contrast to graphene-covered metals, h-BN is not expected to promote galvanic corrosion despite the presence of moist air, as its insulating nature prevents electron conduction to the oxygen atoms. However, the presence of h-BN edges and the confined space between the metal and h-BN may potentially influence the passivation behavior. For metal substrates including Pt, Rh, and Ru, confinement of molecules beneath a 2D layer may enhance metal-catalyzed reactions by modifying the adsorbate–metal interaction and potentially causing reconstruction of the metal surface.\textsuperscript{40–44} In our case, however, the strong interaction between Fe and h-BN suppresses intercalation of molecules; therefore, we suggest that any change in the reactivity of Fe caused by h-BN is likely to occur only locally at the h-BN wrinkles or grain boundaries, which constitute a small proportion of the total surface.

A key consideration in selecting a passivating layer is its stability in its intended operating environment. For certain 2D materials, including MoS\(_2\), WS\(_2\), and black phosphorous, significant structural degradation has been reported under atmospheric conditions at room temperature.\textsuperscript{49–51} However, h-BN is expected to exhibit excellent stability under atmospheric conditions, and indeed the optical images and Raman spectra we obtain (Figure 2) confirm that the h-BN on Fe does not undergo significant deterioration of its structural quality during room temperature air exposure. We further exclude significant defect formation within the domains after room temperature air exposure based on the absence of any component in the XP spectra at \( \sim 193 \text{ eV} \) (Figure S2), which is typically attributed to boron oxide species\textsuperscript{33,35} whose formation has been linked to the loss of N atoms from the h-BN lattice.\textsuperscript{53} This excellent stability in air is also evidenced by the recovery of the initial, dark SEM contrast in h-BN-covered regions after vacuum annealing (Figure 3f). The reduction of the underlying Fe that occurs during this process (as confirmed by XPS in Figure S3) is achieved without accompanying structural damage being detected with SEM. In contrast, SEM following vacuum annealing of air-exposed graphene on Cu and h-BN on Cu reveals that significant etching of the 2D materials occurs. In situ XPS confirms that this happens at temperature by carbothermal reduction of the oxidized Cu substrate for graphene,\textsuperscript{35} and by formation of volatile boron oxides for h-BN, with the extent of damage linked to the amount of substrate oxidation and oxygen species present at the interface as well as the catalytic nature of the substrate (including crystal orientation).\textsuperscript{52} On Cu, which exhibits a weak interaction with graphene and h-BN, rapid decoupling on air exposure allows oxidizing species to readily access the Cu and thus a relatively large oxygen reservoir for etching can develop. Our in situ measurements on Fe herein show no detectable boron oxide species (either in the B 1s or O 1s spectra) during annealing (Figure S3). Nevertheless, we do find that annealing induces some minor degradation of h-BN, as evidenced by the appearance of a boron oxide peak in the B 1s spectrum following subsequent air exposure (Figure S3c), which we attribute to the decoration of defects induced in h-BN during annealing. This indicates that catalytic etching of h-BN on Fe can still occur but that this is relatively minor as only a small oxygen reservoir is formed over the time scales considered here thanks to the strong interfacial interaction that suppresses Fe oxidation. However, this does call into question the viability of using thin h-BN layers as oxidation-resistant coatings under high-temperature conditions,\textsuperscript{5} as the potential for catalytic degradation of h-BN by the substrate it is protecting must be carefully considered. We emphasize that the postannealed Fe surface remains reduced during subsequent exposure to air, as shown in Figure 3f, and hence demonstrate that protection can be re-established through this treatment.

Our results demonstrate that single-layer h-BN can protect Fe from oxidation for several days without undergoing any significant degradation. Although the protection afforded is not superior to that of graphene-covered Ni substrates, which remain reduced for >18 months,\textsuperscript{17} it is comparable to that of graphene on Fe surfaces with the added advantage that the insulating h-BN avoids the formation of a galvanic couple,\textsuperscript{44–56} which may otherwise accelerate corrosion of the underlying metal, as observed for graphene on Cu.\textsuperscript{57} Furthermore, whereas
bare Fe oxidizes almost immediately upon air exposure, we show that h-BN/Fe stacks offer a promising route for maintaining a reduced Fe surface when fabricating devices, where short air exposures between process steps including lithography, development, and lift off, as well as transfer of additional h-BN layers in air, can simplify fabrication or where oxidizing processing steps are required (e.g., atomic-layer/pulsed-laser deposition of oxides, oxygen plasma to remove organic contaminants). Indeed, such integrated processing has been demonstrated by the incorporation of h-BN grown by CVD on Fe electrodes into functional magnetic tunnel junctions, where h-BN serves as both a tunnel barrier and CVD on Fe electrodes into functional magnetic tunnel reservoirs, and after growth, the B3N3H6 leak valve is closed and the thermal stability of h-BN can be a.

**CONCLUSIONS**

In summary, we have shown that single-layer h-BN grown on polycrystalline Fe foils protects the covered Fe surface from oxidation during exposure to moist air for more than 40 h at room temperature, whereas uncovered Fe regions become oxidized. This protection is attributed to the strong interaction between h-BN and the Fe substrate, which suppresses the rapid intercalation of oxidizing species along the interface between them. Over the longer term, slow bulk oxidation of Fe proceeds through the oxide layers formed in the vicinity of h-BN edges and defects, with the Fe eventually becoming oxidized throughout. The behavior observed is in excellent agreement with the model developed by Weatherup et al. to explain the passivation behavior of different graphene-covered metals, demonstrating that this general rationale can be extended to other 2D materials. We confirm that h-BN remains stable during air exposure, with no oxidation of the h-BN detected. On postannealing in vacuum, Fe can be fully reduced, whereas h-BN remains largely intact, confirming that even after extended air exposures the reduced h-BN/Fe stack can be recovered. This annealing is found to induce some defects in h-BN due to catalytic etching by the Fe support, indicating that the thermal stability of h-BN can be affected by the substrate on which it sits. Our results highlight the potential of h-BN films for preserving the surface of ferromagnetic electrodes in a reduced state during processing under oxidizing environments, which is particularly relevant to the transfer-free integration of h-BN in devices such as MTJs.

**METHODS**

**h-BN Growth.** CVD growth is performed using a recipe previously reported. As-received Fe foil (0.1 mm, Alfa Aesar, 99.99% purity) is used as the catalyst substrate for the growth of h-BN domains and films in a customized Aixtron BM3 cold-wall reactor (base pressure less than 10⁻⁹ mbar), using B₃N₃H₆ (6 × 10⁻³ mbar, FluoroChem, >97% purity) as the precursor at ~900 °C. The samples are typically heated in 4 mbar of NH₃ at 100 °C/min up to 750 °C and then at 50 °C/min up to ~900 °C. Immediately after reaching ~900 °C, NH₃ is removed. B₃N₃H₆ is dosed into the chamber through a leak valve (from a liquid reservoir), and after growth, the B₃N₃H₆ leak valve is closed and the heater is turned off. Samples are cooled in vacuum by immediately switching off the heater (cooling rate ~300 °C/min down to ~500 °C, after which it slows down further).

**Transfer.** For optical microscopy and Raman spectroscopy, we transfer the h-BN using an electrochemical bubbling method. We perform the transfer by spin-coating a support layer of poly(methyl methacrylate) (PMMA) onto the sample surface. The sample is placed in a NaOH bath (1 M), and a negative voltage is applied relative to a Pt electrode, which causes H₂ bubbles to evolve at the h-BN/Fe interface, detaching the film from the substrate. The PMMA/h-BN film is rinsed in deionized water and scooped onto a SiO₂ (300 nm) Si wafer where it is left to dry. PMMA is removed by immersing the sample in acetone for ~12 h, followed by a rinse in IPA. The samples are annealed in vacuum at 500 °C for 1 h to remove residual PMMA.

**Characterization.** For the ex situ characterization of h-BN on the catalyst, we use scanning electron microscopy (SEM, Zeiss SigmaVP, 2 kV). Optical images are acquired with a Nikon eclipse ME600L microscope and Raman measurements are performed with a Renishaw In-Via microscope using a 100× objective and 532 nm laser excitation.

XP spectra of the Fe 2p½ core level were collected using a Thermo Scientific ESCALAB 250Xi at an operating pressure <10⁻¹⁰ mbar. X-ray illumination was provided by a microfocused, monochromated Al Kα source with a photon energy of 1486.6 eV and a spot size of ~150 μm diameter. The emitted photoelectrons were collected by a hemispherical energy analyzer with a spectral resolution of ±0.1 eV.

The X-ray photoelectron microscopy/microspectroscopy measurements were carried out with the SPEM instrument at the Escamicroscopy beamline of the Elettra synchrotron facility (Trieste, Italy). The X-ray beam was focused to ~130 nm by a Fresnel zone plate and an order sorting aperture. For both imaging and submicron spectroscopy, a SPECS-PHOIBOS 100 hemispherical electron energy analyzer with an in-house customized multichannel plate detector was used. A photon energy of 1102 eV was employed. The SPEM imaging mode can map the photoelectrons emitted within a selected kinetic energy window by scanning the specimen with respect to the X-ray beam. The SPEM microspectroscopy mode is the typical energy scanning mode employed in any standard XPS system, using a 130 nm X-ray spot size. All binding energies are referenced to measured Fermi edges.

**ASSOCIATED CONTENT**

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsami.7b08717.

SEM image of Fe oxidation along specific channels in the h-BN film; XP spectra of the B 1s core level; SPEM chemical maps acquired with the B 1s, N 1s core-level energies; and XPS data showing the reduction of an Fe foil during annealing in vacuum (PDF)

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**Notes**

The authors declare no competing financial interest.

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